



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Atty. Docket

TED LETAVIC ET AL

US 010631

Serial No. 10/015,640

Group Art Unit: 2814

Filed: DECEMBER 10, 2001

Examiner: N. V. NGO

Title: HIGH FREQUENCY HIGH VOLTAGE SILICON-ON-INSULATOR DEVICE  
WITH MASK VARIABLE INVERSION CHANNEL LAND METHOD FOR FORMING  
THE SAME

Commissioner for Patents  
Washington, D.C. 20231

AMENDMENT

Sir:

In response to the official Office Action dated July 15, 2002, please amend the above-identified application as follows:

IN THE CLAIMS

Kindly cancel Claims 14-20 without prejudice

TECHNOLOGY CENTER 2800

RECEIVED

AUG 23 2002

REMARKS

In the outstanding Official Action, restriction was required as between Claims 1-13, drawn to a semiconductor device and Claims 14-20, drawn to process for making a semiconductor device.

In response, Applicants hereby elect Claims 1-13 for an examination on the merits, without prejudice to Applicants'

2814

#4a  
D. Scott  
8-28-02